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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Arup Bhattacharyya

Title: HIGH-PERFORMANCE ONE-TRANSISTOR MEMORY CELL

Docket No.: 1303.111US1

Filed: July 2, 2003

Examiner: Thomas L Dickey

Serial No.: 10/612,793

Due Date: December 24, 2007

Group Art Unit: 2826



MS Amendment

Commissioner for Patents

P.O. Box 1450

Alexandria, VA 22313-1450

We are transmitting herewith the following attached items (as indicated with an "X"):

- Return postcard.
- Amendment and Response (21 pgs.).
- Communication Concerning Related Applications (1 pg.).
- Information Disclosure Statement (2 pgs.), Form 1449 (1 pg.).
- Authorization to charge Deposit Account 19-0743 in the amount of \$180.00 to cover the fee for consideration of Information Disclosure Statement under 97(c).

If not provided for in a separate paper filed herewith, Please consider this a PETITION FOR EXTENSION OF TIME for sufficient number of months to enter these papers and please charge any additional fees or credit overpayment to Deposit Account No. 19-0743.

SCHWEGMAN, LUNDBERG & WOESSNER, P.A.

Customer Number 21186

By: MLB
Atty: Marvin L. Beekman
Reg. No. 38,377

CERTIFICATE UNDER 37 CFR 1.8: The undersigned hereby certifies that this correspondence is being deposited with the United States Postal Service with sufficient postage as first class mail, in an envelope addressed to: MS Amendment, Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on this 21 day of December, 2007.

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SCHWEGMAN, LUNDBERG & WOESSNER, P.A.

(GENERAL)

S/N 10/612,793



PATENT

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COMMUNICATION CONCERNING RELATED APPLICATIONS

MS Amendment

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Applicant would like to bring to the Examiner's attention the following related applications in the above-identified patent application:

<u>Serial/Patent No.</u>	<u>Filing Date/Issue Date</u>	<u>Attorney Docket</u>	<u>Title</u>
11/477,685	June 28, 2006	1303.111US3	HIGH-PERFORMANCE ONE-TRANSISTOR MEMORY CELL
11/656,602	January 23, 2007	1303.105US3	ONE TRANSISTOR SOI NON-VOLATILE RANDOM ACCESS MEMORY CELL

Continuations and divisionals may be later filed on the cases listed above, or cited to the Examiner in any previous Communication Concerning Related Applications. Applicants request that the Examiner review all continuations and divisionals of the above-listed or previously-cited patent applications before allowing the claims of the present patent application.

Respectfully submitted,

SCHWEGMAN, LUNDBERG & WOESSNER, P.A.
P.O. Box 2938
Minneapolis, MN 55402
(612) 373-6960

Date 12-21-07

By Marvin L. Beekman
Marvin L. Beekman
Reg. No. 38,377

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Lisa Rosecrance
Name

Lisa Rosecrance
Signature